# NSN 5961-01-173-3021

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#### Inclosure Material:

Plastic and metal

# **Overall Length:**

0.730 inches

# **Overall Height:**

0.612 inches

# **Overall Width:**

0.420 inches

# **Mounting Facility Quantity:**

1

#### Internal Configuration:

Junction contact

#### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-220aa

Electrode Internally-electrically Connected To Case:

Collector

#### Mounting Method:

Unthreaded hole

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

75.0 collector to base voltage/static/emitter open and 5.0 emitter to base voltage, static, collector open and 65.0 collector-to-emitter, resistance between base and emitter

# **Current Rating Per Characteristic:**

7.00 amperes source cutoff current and 3.00 amperes source cutoff current

#### Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector preset

#### **Transfer Ratio:**

100.0 static forward current transfer ratio, common-emitter

# Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

# **Special Features:**

Junction pattern arrangement: npn

# **Terminal Type And Quantity:**

3 pin

# **Specification Data:**

80131-release6145a professional/industrial association specification

# Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

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